

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	39	goebel-bernd.in.	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 08:33
L2	137727	DRAM or "dynamic random access memory"	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 08:33
L5	401	oxide and strap and irradiat\$4	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 08:39
L6	39	5 and 2	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 08:37
L9	61	2 and strap and irradiat\$4	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 08:40
L10	58	"buried strap" and (irradiat\$4 or "ion beam")	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 08:59
L11	1776	"strap" and (irradiat\$4 or "ion beam")	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 08:59
L12	130	"strap" and (irradiat\$4 or "ion beam") and trench and etch\$4	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 09:15

## EAST Search History

L13	1832	"strap" and trench and etch\$4	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 11:17
L15	1276	13 and 2	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 09:16
L16	1078	15 and polysilicon	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 09:17
L17	964	"strap" and trench and etch\$4 and capacitor and sidewall	US-PGPUB; USPAT; USOCR; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/10 11:18